Product data sheet

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NXP Semiconductors



BF991

FEATURES

 Protected against excessive input voltage surges by integrated back-to-back diodes between gates and source.

APPLICATIONS

- VHF applications such as:
 - VHF television tuners and FM tuners
 - Professional communication equipment.

PINNING

PIN	SYMBOL	DESCRIPTION
1	s, b	source
2	d	drain
3	g ₂	gate 2
4	9 1	gate 1

DESCRIPTION

Depletion type field-effect transistor in a plastic SOT143 microminiature package with interconnected source and substrate.

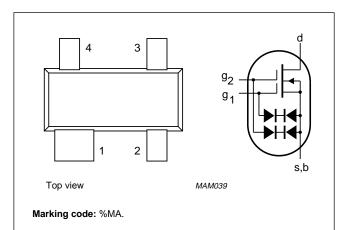


Fig.1 Simplified outline (SOT143) and symbol.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _{DS}	drain-source voltage		_	20	V
ID	drain current		_	20	mA
P _{tot}	total power dissipation	up to T _{amb} = 60 °C	-	200	mW
Tj	junction temperature		-	150	°C
Y _{fs}	transfer admittance	$f = 1 \text{ kHz}; I_D = 10 \text{ mA}; V_{DS} = 10 \text{ V}; V_{G2-S} = 4 \text{ V}$	14	-	mS
C _{ig1-s}	input capacitance at gate 1	f = 1 MHz; I_D = 10 mA; V_{DS} = 10 V; V_{G2-S} = 4 V	2.1	-	pF
C _{rs}	feedback capacitance	f = 1 MHz; I_D = 10 mA; V_{DS} = 10 V; V_{G2-S} = 4 V	20	-	fF
F	noise figure	$ f = 200 \text{ MHz}; \text{G}_{\text{S}} = 2 \text{ mS}; \text{B}_{\text{S}} = \text{B}_{\text{Sopt}}; \\ \text{I}_{\text{D}} = 10 \text{ mA}; \text{V}_{\text{DS}} = 10 \text{ V}; \text{V}_{\text{G2-S}} = 4 \text{ V} $	1	2	dB

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LIMITING VALUES

In according with the Absolute Maximum Rating System (IEC 134).

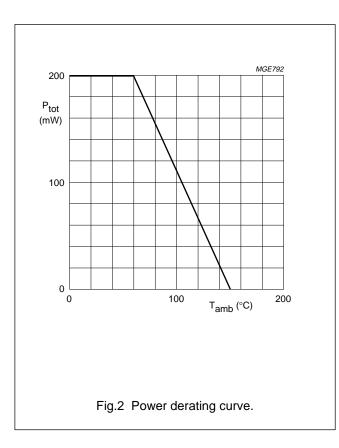
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	drain-source voltage		-	20	V
I _D	drain current (DC)		-	20	mA
I _{D(AV)}	average drain current		-	20	mA
I _{G1-S}	gate 1-source current		-	±10	mA
I _{G2-S}	gate 2-source current		-	±10	mA
P _{tot}	total power dissipation	up to T _{amb} = 60 °C; note 1	_	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R _{th j-a}	thermal resistance from junction to ambient	in free air; note 1	460	K/W	

Note to the Limiting values and the Thermal characteristics

1. Device mounted on a ceramic substrate of $8\times10\times0.7$ mm.



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STATIC CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{G1-SS}	gate 1 cut-off current	$V_{G1-S} = 5 V; V_{G2-S} = V_{DS} = 0$	-	50	nA
I _{G2-SS}	gate 2 cut-off current	$V_{G2-S} = 5 V; V_{G1-S} = V_{DS} = 0$	-	50	nA
I _{DSS}	drain current	$V_{DS} = 10 \text{ V}; V_{G1-S} = 0; V_{G2-S} = 4 \text{ V}$	4	25	mA
V _{(BR)G1-SS}	gate 1-source breakdown voltage	$I_{G1-SS} = 10 \text{ mA}; V_{G2-S} = V_{DS} = 0$	6	20	V
V _{(BR)G2-SS}	gate 2-source breakdown voltage	$I_{G2-SS} = 10 \text{ mA}; V_{G1-S} = V_{DS} = 0$	6	20	V
V _{(P)G1-S}	gate 1-source cut-off voltage	$I_D = 20 \ \mu\text{A}; \ V_{DS} = 10 \ \text{V}; \ V_{G2-S} = 4 \ \text{V}$	-	-2.5	V
V _{(P)G2-S}	gate 2-source cut-off voltage	$I_D = 20 \ \mu\text{A}; \ V_{DS} = 10 \ V; \ V_{G1-S} = 0$	-	-2.5	V

DYNAMIC CHARACTERISTICS

Measuring conditions (common source): I_D = 10 mA; V_{DS} = 10 V; V_{G2-S} = 4 V; T_{amb} = 25 °C.

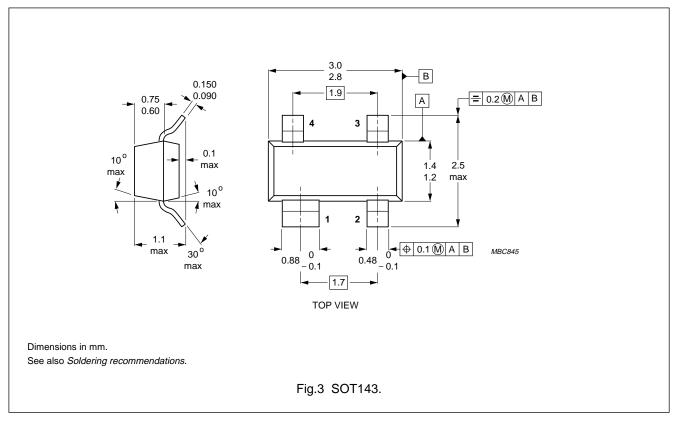
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Y _{fs}	transfer admittance	f = 1 kHz	10	14	-	mS
C _{ig1-s}	input capacitance at gate 1	f = 1 MHz	-	2.1	-	pF
C _{ig2-s}	input capacitance at gate 2	f = 1 MHz	-	1	-	pF
C _{rs}	feedback capacitance	f = 1 MHz	-	20	-	fF
C _{os}	output capacitance	f = 1 MHz	-	1.1	-	pF
F	noise figure	$f = 100 \text{ MHz}; G_S = 1 \text{ mS}; B_S = B_{Sopt}$	-	0.7	1.7	dB
		$f = 200 \text{ MHz}; G_S = 2 \text{ mS}; B_S = B_{Sopt}$	-	1	2	dB
G _{tr}	transducer gain; note 1	f = 100 MHz; G_S = 1 mS; B_S = B_{Sopt} ; G _L = 0.5 mS; B_L = B_{Lopt}	-	29	_	dB
		$ f = 200 \text{ MHz}; \text{G}_{\text{S}} = 2 \text{ mS}; \text{B}_{\text{S}} = \text{B}_{\text{Sopt}}; \\ \text{G}_{\text{L}} = 0.5 \text{ mS}; \text{B}_{\text{L}} = \text{B}_{\text{Lopt}} $	_	26	-	dB

Note

1. Crystal mounted in a SOT103 package.

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PACKAGE OUTLINE



Legal information

Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Revision history

Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
BF991_N_3	20071120	Product data sheet	-	BF991_2
Modifications:	 Fig. 1 on pa 	ige 2; Figure note changed		
BF991_2	19910401	Product specification	-	BF991_SF_1
BF991_SF_1	-	-	-	-

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Date of release: 20 November 2007 Document identifier: BF991_N_3

